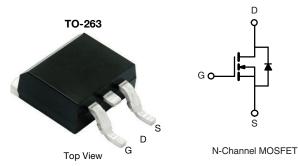


Automotive N-Channel 100 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	100					
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.024					
$R_{DS(on)}$ (Ω) at V_{GS} = 4.5 V	0.027					
I _D (A)	47					
Configuration	Single					
Package	TO-263					



FEATURES

- TrenchFET® power MOSFET
- · Package with low thermal resistance
- AEC-Q101 qualified ^c
- 100 % $\rm R_g$ and UIS tested
- Material categorization for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



ABSOLUTE MAXIMUM RATINGS	(T _C = 25 °C, unless	otherwise noted	(k	
PARAMETER	SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V _{DS}	100	V
Gate-Source Voltage	V _{GS}	± 20	v	
Continuous Drain Current	T _C = 25 °C	1	47	
	T _C = 125 °C	- I _D	27	
Continuous Source Current (Diode Conduction	on)	I _S	47	A
Pulsed Drain Current ^a		I _{DM}	189	
Single Pulse Avalanche Current	ngle Pulse Avalanche Current L = 0.1 mH		43	
Single Pulse Avalanche Energy		E _{AS}	92	mJ
Maniana Damar Diasis atian 3	T _C = 25 °C	D	136	W
Maximum Power Dissipation ^a	T _C = 125 °C	P _D	45	VV
Operating Junction and Storage Temperature	Range	T _J , T _{stg}	-55 to +175	°C

THERMAL RESISTANCE RATINGS						
PARAMETER		SYMBOL	LIMIT	UNIT		
Junction-to-Ambient	PCB Mount ^b	R _{thJA}	40	°C/W		
Junction-to-Case (Drain)			1.1	0/10		

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. When mounted on 1" square PCB (FR4 material).

c. Parametric verification ongoing.



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PARAMETER	SYMBOL	TES	MIN.	TYP.	MAX.	UNIT		
Static								
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0, I_D = 250 \ \mu A$		100	-	-	v	
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$		2.0	2.5	v	
Gate-Source Leakage	I _{GSS}	V _{DS} =	$V_{DS} = 0 V, V_{GS} = \pm 20 V$		-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = 100 V	-	-	1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 100 V, T _J = 125 °C	-	-	50	μA	
		$V_{GS} = 0 V$	V _{DS} = 100 V, T _J = 175 °C	-	-	250		
On-State Drain Current ^a	I _{D(on)}	$V_{GS} = 10 V$	$V_{DS} \ge 5 V$	120	-	-	Α	
		$V_{GS} = 10 V$	I _D = 40 A	-	0.017	0.024		
Durin Course On Otata Desistance 3		$V_{GS} = 10 V$	I _D = 40 A, T _J = 125 °C	-	-	0.048	Ω	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 40 A, T _J = 175 °C	-	-	0.061		
		$V_{GS} = 4.5 V$	I _D = 20 A	-	0.020	0.027		
Forward Transconductance b	g fs	V _{DS} = 15 V, I _D = 40 A		-	85	-	S	
Dynamic ^b	•	-			•		•	
Input Capacitance	C _{iss}				2893	3620		
Output Capacitance	Coss	$V_{GS} = 0 V$	V _{DS} = 25 V, f = 1 MHz	-	321	400	pF	
Reverse Transfer Capacitance	C _{rss}			-	126	160		
Total Gate Charge ^c	Qg			-	48	72	nC	
Gate-Source Charge ^c	Q _{gs}	$V_{GS} = 10 V$	$V_{DS} = 50 \text{ V}, I_D = 40 \text{ A}$	-	10	-		
Gate-Drain Charge ^c	Q _{gd}			-	10	-		
Gate Resistance	R _g	f = 1 MHz		0.4	1	3.5	Ω	
Turn-On Delay Time ^c	t _{d(on)}	$V_{DD} = 50 \text{ V}, \text{ R}_L = 1.06 \ \Omega$ $I_D \cong 47 \text{ A}, \text{ V}_{\text{GEN}} = 10 \text{ V}, \text{ R}_g = 1 \ \Omega$		-	10	15	- ns	
Rise Time ^c	t _r			-	6	9		
Turn-Off Delay Time ^c	t _{d(off)}			-	32	48		
Fall Time ^c	t _f			-	6	9		
Source-Drain Diode Ratings and Chara	acteristics b							
Pulsed Current ^a	I _{SM}			-	-	189	Α	
Forward Voltage	V _{SD}	IF	= 40 A, V _{GS} = 0	-	0.85	1.5	V	

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



4

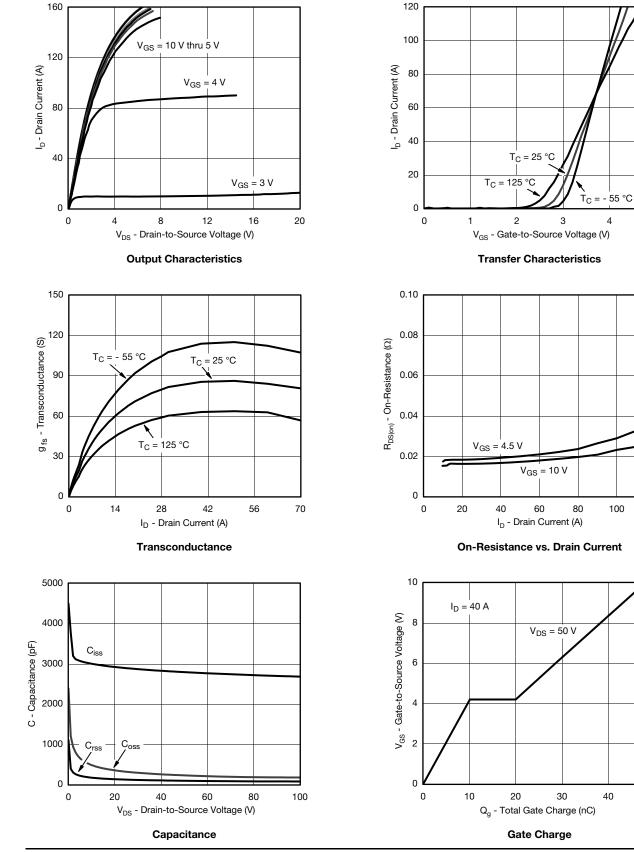
100

120

5

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TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



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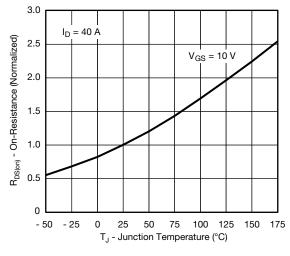
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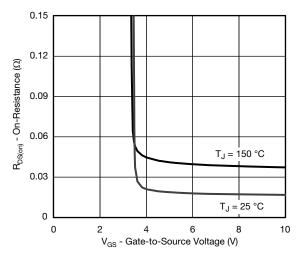
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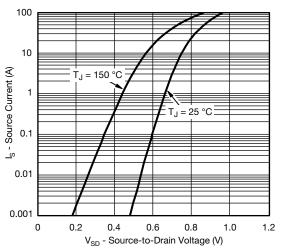
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



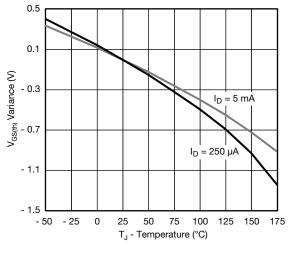
On-Resistance vs. Junction Temperature



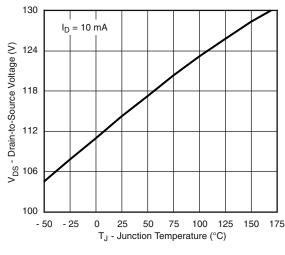
On-Resistance vs. Gate-to-Source Voltage



Source Drain Diode Forward Voltage







Drain Source Breakdown vs. Junction Temperature 4

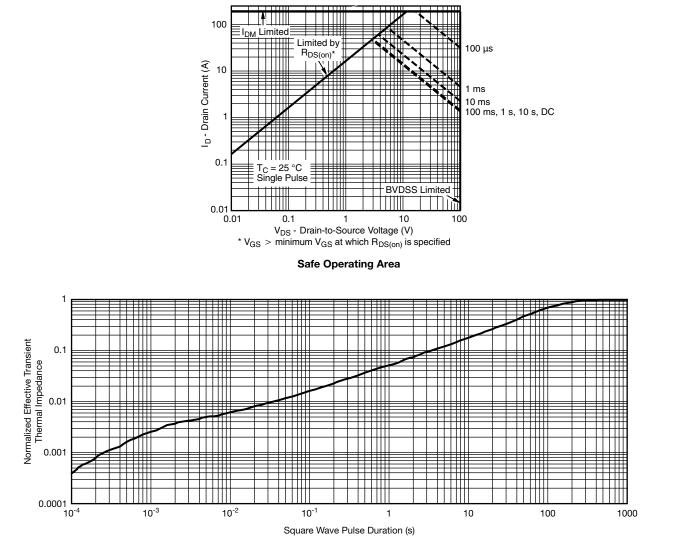
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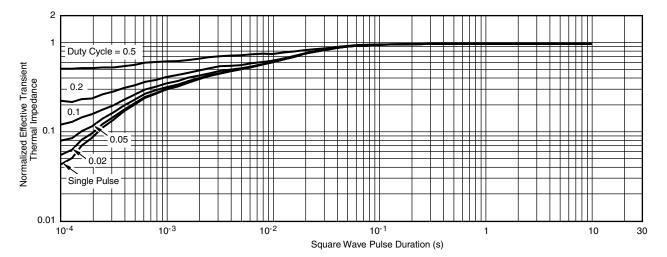
THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

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REVISION HISTORY ^a				
REVISION	DATE	DESCRIPTION OF CHANGE		
D	04-Aug-15	Revised R _g minimum limit		

Note

a. As of April 2014



TO-263 (D²PAK): 3-LEAD









DETAIL A (ROTATED 90°)



		INCHES		MILLIMETERS		
DIM.		MIN.	MAX.	MIN.	MAX.	
A		0.160	0.190	4.064	4.826	
b		0.020	0.039	0.508	0.990	
	b1	0.020	0.035	0.508	0.889	
	b2	0.045	0.055	1.143	1.397	
с*	Thin lead	0.013	0.018	0.330	0.457	
C	Thick lead	0.023	0.028	0.584	0.711	
c1	Thin lead	0.013	0.017	0.330	0.431	
CI	Thick lead	0.023	0.027	0.584	0.685	
	c2	0.045	0.055	1.143	1.397	
	D	0.340	0.380	8.636	9.652	
	D1	0.220	0.240	5.588	6.096	
	D2	0.038	0.042	0.965	1.067	
	D3	0.045	0.055	1.143	1.397	
	D4	0.044	0.052	1.118	1.321	
	E	0.380	0.410	9.652	10.414	
	E1	0.245	-	6.223	-	
E2		0.355	0.375	9.017	9.525	
E3		0.072	0.078	1.829	1.981	
е		0.100	BSC	2.54 BSC		
К		0.045	0.055	1.143	1.397	
L		0.575	0.625	14.605	15.875	
L1		0.090	0.110	2.286	2.794	
L2		0.040	0.055	1.016	1.397	
L3		0.050	0.070	1.270	1.778	
L4		0.010 BSC		0.254 BSC		
М		-	0.002	-	0.050	
ECN: T13-0707-Rev. K, 30-Sep-13 DWG: 5843						

Notes

- 1. Plane B includes maximum features of heat sink tab and plastic. 2. No more than 25 % of L1 can fall above seating plane by
- max. 8 mils.3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB.
 - Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

This feature is for thick lead.

Revison: 30-Sep-13



RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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